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Le87501 **PLC Single Channel Line Driver** Line Driver BD870 Series

Preliminary Data Sheet

Features

- 16-pin. 4x4 mm QFN Package
- Low Power Operation
- Class AB Operation
- Enable/Disable Control
- Capable of Driving Line Impedance Between . 12 Ω to 100 Ω
- Operations to 86 MHz .
- **RoHS** Compliant

Applications

- Power Line Communications
- Home Networking
- HPNA
- G.HN

Description

The Le87501 is a single channel line driver designed to work in Home Plug Alliance HPAV2 systems.

When enabled, the operating level can be set to Full, 90% or 80% power. The Le87501 delivers superior performance and can drive a line impedance of 100 Ω down to 12 Ω through a proper transformer.

In addition, the Le87501 features a Standby state which forces the driver into a long-term sleep mode.

Document ID# PD-000246513 Version 3

> Ordering Information 16-pin QFN Green Pkg.

Le87501NQC

Trav

August 2018

The green package is Halogen free and meets RoHS 2 Directive 2011/65/EU of the European Council to minimize the environmental impact of electrical equipment.

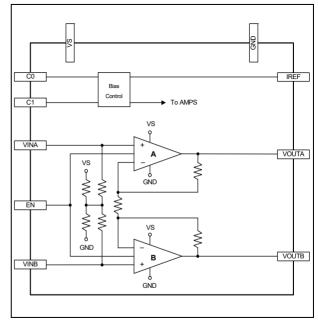


Figure 1 - Block Diagram

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Pin Diagram

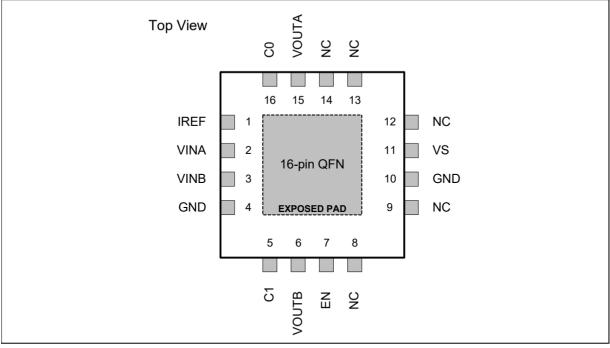


Figure 2 - Pin Diagram

Note 1: Pin 1 is marked for orientation.

Note 2: The device incorporates an exposed die pad on the underside of its package. The pad acts as a heat sink and must be connected to a copper plane through thermal vias for proper heat dissipation. It is electrically isolated and may be connected to GND.

Pin Description

Pin #	Pin Name	Туре	Description	
1	IREF	Input	Device Internal Reference Current. Connect a resistor to GND.	
2	VINA	Input	Amplifier A input	
3	VINB	Input	Amplifier B input	
4, 10	GND	Ground	Low noise analog ground	
5, 16	C1, C0	Inputs	Control inputs, sets operation state when channel enabled	
6	VOUTB	Output	Amplifier B output	
7	EN	Input	Enable/Disable control	
8, 9, 12, 13, 14	NC		No connects, no internal connection	
11	VS	Power	Power supply	
15	VOUTA	Output	Amplifier A output	

Table 1 - Pin Descriptions



Absolute Maximum Ratings

Stresses above the values listed under *Absolute Maximum Ratings* can cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods can affect device reliability.

Storage Temperature	$-65^{\circ}C \le T_A \le +150^{\circ}C$				
Operating Junction Temperature	$-40^{\circ}C \leq T_J \leq +150^{\circ}C^1$				
VS to GND	–0.3 V to +16.0 V				
Driver inputs VINA/B	VS to GND				
Control inputs C0/1, EN	–0.3 V to +4.0 V				
Continuous Driver Output Current	200 mA _{RMS}				
ESD Immunity (Human Body Model)	JESD22 Class 2 compliant				
ESD Immunity (Charge Device Model)	JESD22 Class IV compliant				
Note 1: Continuous operation above +145°C junction temperature may degrade device long term reliability.					

Table 2 - Absolute Maximum Ratings

Thermal Resistance

The thermal performance of a thermally enhanced package is assured through optimized printed circuit board layout. Specified performance requires that the exposed thermal pad be soldered to an equally sized exposed copper surface, which, in turn, conducts heat through multiple vias to larger internal copper planes.

Package Assembly

The green package devices are assembled with enhanced, environmental compatible lead-free, halogen-free, and antimony-free materials. The leads possess a matte-tin plating which is compatible with conventional board assembly processes or newer lead-free board assembly processes.

Refer to IPC/JEDEC J-Std-020 for recommended peak soldering temperature and solder reflow temperature profile.

Operating Ranges

Microsemi guarantees the performance of this device over the 0°C to +85°C temperature range by conducting electrical characterization and a single insertion production test coupled with periodic sampling. These procedures comply with the Telcordia GR-357-CORE Generic Requirements for Assuring the Reliability of Components Used in Telecommunications Equipment.

Ambient temperature	0°C to +85°C
VS with respect to GND	+10 to +15 V

Table 3 - Operation Ranges



Device Specifications

VS = +12 V. Device in Enable Full Power state using the Basic Test Circuit (Figure 3), unless otherwise specified.

Typical Conditions: $T_A = 25^{\circ}C$.

Min/Max Parameters: $T_A = 0^{\circ}C$ to +85°C

Symbol	Parameter	Parameter Condition Min		Тур.	Max.	Unit	Notes
Power						•	
I _{VS}	Quiescent Supply Current	VINA/B floating					
		Enable Full Power State	42	60	70	mA	
		Enable 90% Power State	40	52	63	mA	
		Enable 80% Power State	37	45	56	mA	
		Disable State	0.6	1.0	1.2	mA	
		Standby State	0.3	0.65	1.0	mA	
Control I	nput (C0/1, EN) Characteristics						1
V _{IH}	Input High Voltage		1.2		3.6	V	
V _{IL}	Input Low Voltage		-0.3		+0.6	V	
IIH	Input High Current		0	75	100	μA	
IIL	Input Low Current		0	10	15	μA	
Channel	Input (VINA/B) Characteristics						
V _{IH}	Input Offset Voltage		0		35	mV	
Zl	Differential Input Impedance	VINA – VINB at 2 MHz	12	15	18	kΩ	2
Channel	Output (VOUTA/B) Characteristics						
Vo	Output Voltage		9.5		12	V	
I _O	Output Current	RLoad = 10 Ω		600		mA	
Z _O	Disabled Output Impedance	Differential		1400		Ω	
Channel	Dynamic Characteristics						
	Voltage Gain	VOUT/VIN at 1 MHz	6.0	6.5	7.0	V/V	
	Bandwidth	-3 dB		170		MHz	
Noise	Input Referred Noise	Differential		8		nV/√Hz	
MTPR	Multi Tone Power Ratio	PLoad = 40 mW					
		0.5 - 30 MHz		-62		dBc	
		30 - 86 MHz		-32		dBc	
	Enable Time	Between Disable and any		500		ns	
	Disable Time	Power-up state		500		ns	
TSD	Thermal Shutdown Temperature			170		°C	

Table 4 - Electrical Specifications



Test Circuit

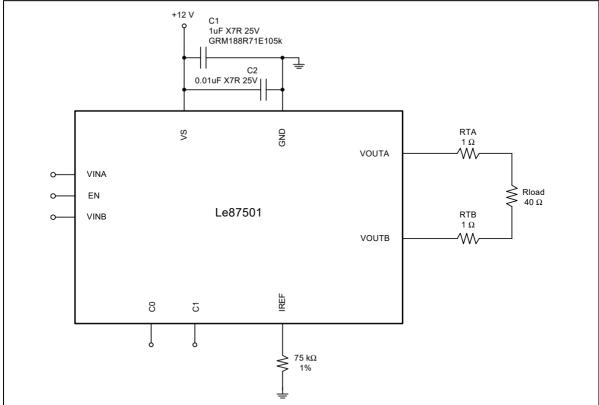


Figure 3 - Basic Test Circuit



Operation States

Operation state control is depicted in <u>Table 5</u>.

For active operation, the driver will either be in Enable state (Power-up mode) or Disable state (Power-down mode). A Standby state (long-term Sleep mode) is also provided.

EN controls the driver's power mode as follows:

• EN = 0, channel A/B in Power-down mode; EN = 1, channel A/B in Power-up mode

C0 and C1 control state selection. A setting of C0 = C1 = 0 overrides EN and places the driver in Standby state.

Standby is the default state when power is initially supplied.

EN	C1	C0	Device State	Mode
1	1	1	Enable Full Power	
1	0	1	Enable 90% Power	Power-up
1	1	0	Enable 80% Power	
Х	0	0	Standby	Sleep
0	1	1		
0	1	0	Disable	Power-down
0	0	1		

Table 5 - Operation State Control

X = Don't care.

Le87501



Typical Performance Characteristics

Some typical performance characteristics are shown in Figure 4, Figure 5 and Figure 6.

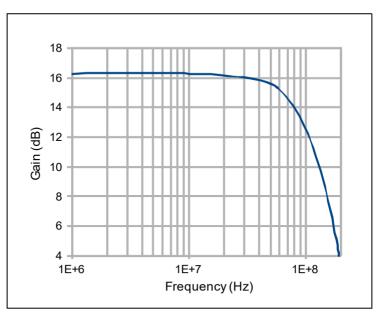


Figure 4 - Differential Gain

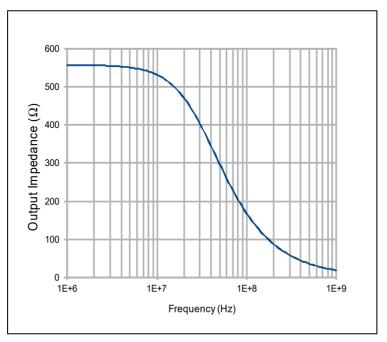


Figure 5 - Disabled Output Impedance



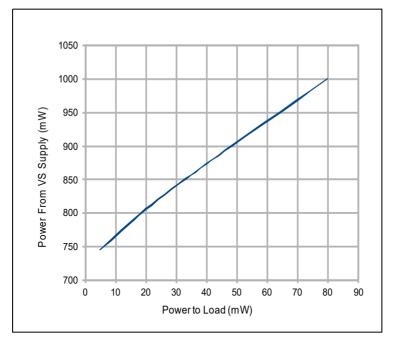


Figure 6 - Supply Power Versus Load Power



Applications

The Le87501 integrates a high-power line driver amplifier designed for low distortion for signals up to 86 MHz. A typical application interface circuit is shown in Figure 7.

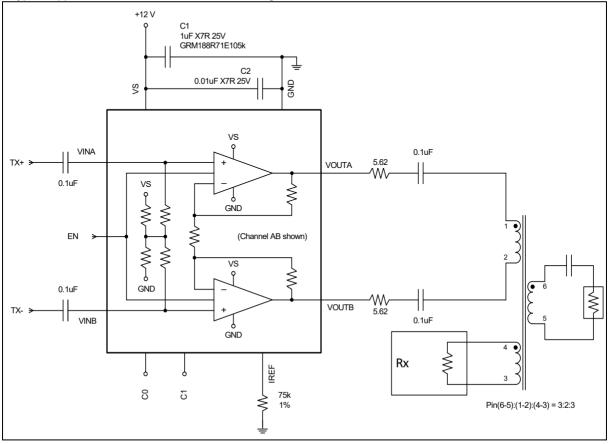


Figure 7 - Typical Application Circuit

The amplifiers have identical positive gain connections with common-mode rejection. Any DC input errors are duplicated and create common-mode rather than differential line errors.

Input Considerations

The driving source impedance should be less than 100 nH to avoid any ringing or oscillation.

Output Driving Considerations

The internal metallization is designed to drive 200 mA_{RMS} sinusoidal current and there is no current limit mechanism. Driving lines without a series resistor is not recommended.

If a DC current path exists between the two outputs, a DC current can flow through the outputs. To avoid DC current flow, the most effective solution is to place DC blocking capacitors in series with the output as shown in Figure 7.

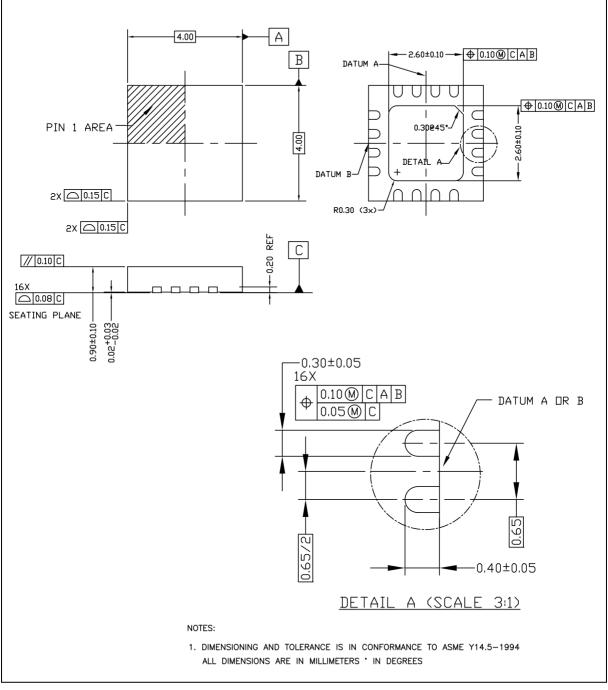
Power Supplies and Component Placement

The power supply should be well bypassed with decoupling placed close to the Le87501.



Physical Dimensions

16-Pin QFN



Note:

Packages may have mold tooling markings on the surface. These markings have no impact on the form, fit or function of the device. Markings will vary with the mold tool used in manufacturing.

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